SEIKO EPSON CORPORATION

CRYSTAL OSCILLATOR (Programmable) **OUTPUT: CMOS**





Product Number

SG-8018CG: X1G005601xxxx00 SG-8018CE: X1G005591xxxx00 SG-8018CB: X1G005581xxxx00 SG-8018CA: X1G005571xxxx00

SG-8018 series

: 0.67 MHz to 170 MHz (1 ppm Step) • Frequency range

 Supply voltage : 1.62 V to 3.63 V

: Output enable (OE) or Standby (ST) Function

• Frequency tolerance: ±50 ppm (-40 °C to +105 °C)

Including frequency aging(+25 °C, 10 years)

• PLL technology to enable short lead time

• Available field oscillator programmer "SG-Writer II"



 $2.5 \times 2.0 \text{ mm}$ $3.2 \times 2.5 \text{ mm}$





 $5.0 \times 3.2 \text{ mm}$ $7.0 \times 5.0 \text{ mm}$

| Specifications (| (characteristics) | Ì |
|------------------|-------------------|---|
| | | |

| Specifications (characteristics) | | | | | | | | | | |
|---|---------|--------------------|--|---|-------------|--|---|----------------------------------|--|--|
| Item Symbol | | Specifications | | | | Conditions/Remarks | | | | |
| Supply voltage | | Vcc | 1.80 \ | • | 2.50 V Typ. | 3.30 V Typ. | | | _ | |
| 11,7 | | | 1.62 V to 1.98 V | 1.62 V to 1.98 V 1.98 V to 2.20 V 2.20 V to 2.80 V 2.70 V to 3.63 V | | | | | | |
| Output frequency range fo | | | 0.67 MHz to 170 MHz | | | | | | | |
| Storage tempera | | T_stg | -40 °C to +125 °C | | | | Storage as single product. | | | |
| Operating temper | | T_use | -40 °C to +105 °C | | | | - | | | |
| Frequency tolera | ance | f_tol | | | | T_use = -40 °C to +105 °C | | | | |
| | | | 3.2 mA Max. | 3.3 mA Max. | 3.4 mA Max. | 3.5 mA Max. | T_use = +105 °C | No load, f ₀ = 20 MHz | | |
| Current consum | ption | Icc | | nA Typ. | 2.9 mA Typ. | 3.0 mA Typ. | T_use = +25 °C | , .5 _5 | | |
| | • | | 5.5 mA Max. | 5.8 mA Max. | 6.7 mA Max. | 8.1 mA Max. | T_use = +105 °C | No loa | d, f ₀ = 170 MHz | |
| | | | | nA Typ. | 5.7 mA Typ. | 6.8 mA Typ. | T_use = +25 °C | · | | |
| Output disable of | urrent | I_dis | 3.2 mA Max. | 3.2 mA Max. | 3.3 mA Max. | 3.5 mA Max. | , , , | | | |
| Standby current | | I std | 0.9 μA Max. | 1.0 µA Max. | 1.5 μA Max. | 2.5 μA Max. | T_use = +105 °C | ST = 0 | SND | |
| , | | | 0.3 μA Typ. | 0.4 μA Typ. | 0.5 μA Typ. | 1.1 μA Typ. | T_use = +25 °C | | | |
| Symmetry | | SYM | | 45 % 1 | o 55 % | | 50 % V _{CC} Level | | | |
| | | | | | | | I _{OH} /I _{OL} Conditions Rise/Fall time | \ / | [mA] *A *B *C *D | |
| | | V _{OH} | | 90 % V _{CC} Min. | | | Default (f _O > 40 MHz) | V _{CC} | -2.5 -3.5 -4.0 -5.0 | |
| | | • 011 | | | | | Fast | I _{OL} | 2.5 3.5 4.0 5.0 | |
| Output voltage | | | | | | Default (f _O ≤ 40 MHz) | la | -1.5 -2.0 -2.5 -3.0 | | |
| (DC characterist | tics) | VoL | | | | | Default (Io ≤ 40 MHZ) | I _{OL} | 1.5 2.0 2.5 3.0 | |
| | | | | 40.0/ \/ | May | | Slow | I _{OH} | -1.0 -1.5 -2.0 -2.5 | |
| | | | | 10 % V _{CC} Max. | | | *^ 1 62 | I _{OL} | 1.0 1.5 2.0 2.5 98 V, *B: 1.98 V to 2.20 V, | |
| | | | | | | *C: 2.20 V to 2.80 V, *D: 2.70 V to 3.63 V | | | | |
| Output load con | dition | L_CMOS | 15 pF Max. | | | | | | - | |
| Innut valtage | | V _{IH} | 70 % V _{CC} Min. | | | | OE or ST | | | |
| Input voltage | | V _{IL} | 30 % V _{CC} Max. | | | | | | | |
| | Default | | 3.0 ns Max. | | | f _O > 40 MHz | | | | |
| Rise time | Delault | | 6.0 ns Max. | | | f ₀ ≤ 40 MHz 20 % - 80 % V _{CC} , | | | | |
| /Fall time | Fast | tr/tf | 3.0 ns Max. | | | f _O = 0.67 MHz to 17 | 70 MHz | MHz L_CMOS = 15 pF | | |
| | Slow | | 10.0 ns Max. | | | f ₀ = 0.67 MHz to 20 | 0 MHz | | | |
| Output disable time (OE) Output disable time (ST) | | tstp_oe tstp_st | 1 μs Max. | | | | Measured from the time OE or ST pin crosses 30 % Vcc | | | |
| Output enable time (OE) | | tsta_oe | 1 μs Max. | | | Measured from the time OE pin crosses 70 % V _{CC} | | | | |
| Output enable time (ST) | | tsta_st | 3 ms Max. | | | Measured from the time \overline{ST} pin crosses 70 % V _{CC} | | | | |
| Start-up time | | t_str | 3 ms Max. | | | Measured from the time V_{CC} reaches its rated minimum value, 1.62 V | | | | |
| Frequency aging f_ | | f_age | This is included in frequency tolerance specification. | | | | +25 °C, 10 years | | | |

^{*1} Frequency tolerance includes initial frequency tolerance, frequency / temperature characteristics, frequency / voltage coefficient, frequency / load coefficient and frequency aging (+25 °C, 10 years).

Pin description

| Pin | Name | I/O type | Function | | |
|-----|-----------------|----------|---------------|--|--|
| | OE | Input | Output enable | High*2: Specified frequency output from OUT pin | |
| | | | | Low: Out pin is low (weak pull down), only output driver is disabled. | |
| 1 | | | | High ^{*2} : Specified frequency output from OUT pin | |
| | ST | Input | Standby | Low: Out pin is low (weak pull down), | |
| | | | | Device goes to standby mode. Supply current reduces to the least as I_std. | |
| 2 | GND | Power | Ground | | |
| 3 | OUT | Output | Clock output | | |
| 4 | V _{cc} | Power | Power supply | | |

^{*2} Please do not use the OE/ST terminal in the open state.



Product Name

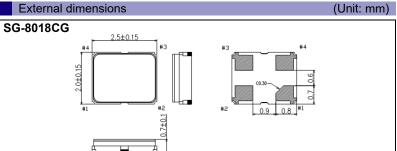
$\frac{\text{SG-8018CG}}{\textcircled{1}} \stackrel{25.000000\text{MHz}}{\textcircled{3}} \stackrel{\underline{\textbf{T}} \, \underline{\textbf{J}} \, \underline{\textbf{H}} \, \underline{\textbf{P}} \, \underline{\textbf{A}}}{\textcircled{4.5} \, \textcircled{6.78}}$

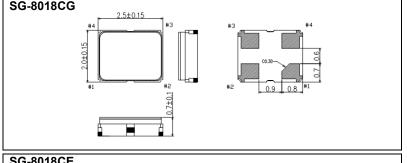
- 1) Model 2) Package type 3) Frequency
- 4 Supply voltage (T: 1.8 V to 3.3 V Typ.)
- ⑤Frequency tolerance (J: ±50 × 10⁻⁶)
- 6 Operating temperature (H: -40 °C to +105 °C)
- 7)Function 8)Rise/Fall time

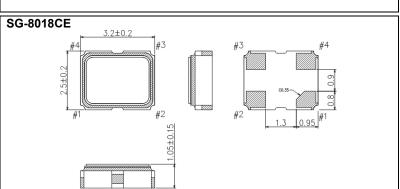
| ②Package type | | | |
|---------------|-----------------|--|--|
| CG | 2.5 mm × 2.0 mm | | |
| CE | 3.2 mm × 2.5 mm | | |
| СВ | 5.0 mm × 3.2 mm | | |
| CA | 7.0 mm × 5.0 mm | | |

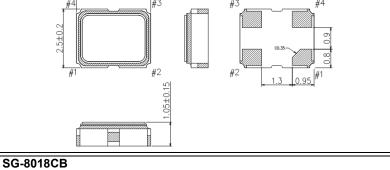
| ⑦Function | | | | |
|--------------|--|--|--|--|
| utput enable | | | | |
| tandby | | | | |
| | | | | |

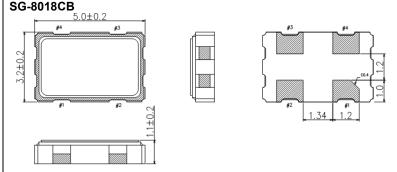
| ı | ®Rise time/Fall time | | | | |
|---|----------------------|---------|--|--|--|
| | Α | Default | | | |
| | В | Fast | | | |
| | С | Slow | | | |

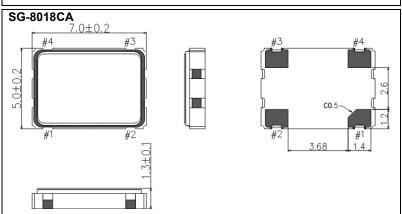


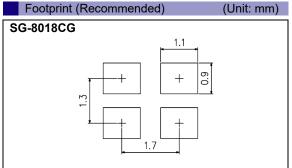


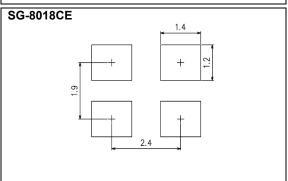


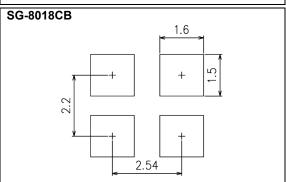


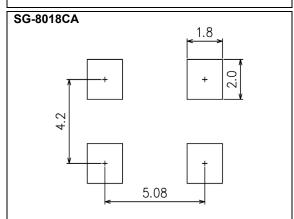












In order to achieve optimum jitter performance, the 0.1 μF capacitor between V_{CC} and GND should be placed. It is also recommended that the capacitors are placed on the device side of the PCB, as close to the device as possible and connected together with short wiring pattern.

Explanation of the mark that are using it for the catalog



▶Pb free.



► Complies with EU RoHS directive.

*About the products without the Pb-free mark.

Contains Pb in products exempted by EU RoHS directive.

(Contains Pb in sealing glass, high melting temperature type solder or other.)



▶ Designed for automotive general equipment.



▶ Designed for automotive applications related to driving and safety.

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